

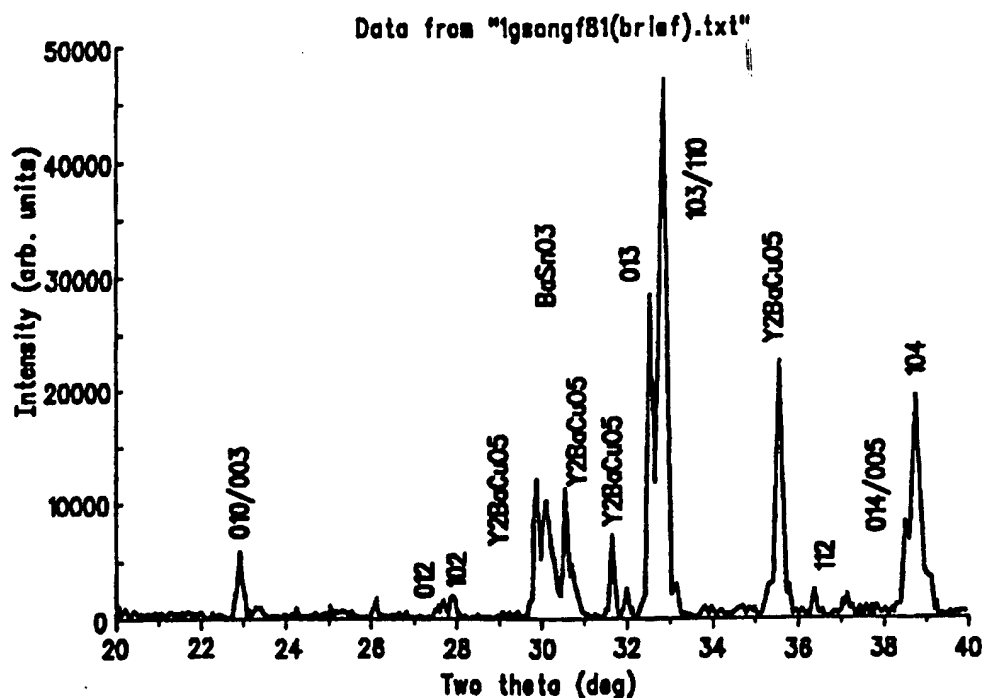
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(21) International Application Number: PCT/US95/16995 (22) International Filing Date: 29 December 1995 (29.12.95) (30) Priority Data: 08/365,848 29 December 1994 (29.12.94) US (71) Applicant: UNIVERSITY OF HAWAII [US/US]; Suite 280, 2800 Woodlawn Drive, Honolulu, HI 96822 (US). (72) Inventors: SONG, Steven, Yi; 1936 Wilder Avenue, No. 203, Honolulu, HI 96822 (US). GAINES, James, R.; 3594 Akaka Place, Honolulu, HI 96822 (US). (74) Agents: SHERIDAN, James, A. et al.; Flehr, Hohbach, Test, Albritton & Herbert, Suite 3400, 4 Embarcadero Center, San Francisco, CA 94111-4187 (US).		(81) Designated States: AL, AM, AT, AU, AZ, BB, BG, BR, BY, CA, CH, CN, CZ, DE, DK, EE, ES, FI, GB, GE, HU, IS, JP, KE, KG, KP, KR, KZ, LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, TJ, TM, TT, UA, UG, UZ, VN, ARIPO patent (KE, LS, MW, SD, SZ, UG), European patent (AT, BE, CH, DE, DK, ES, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, ML, MR, NE, SN, TD, TG). Published <i>With international search report.</i> <i>Before the expiration of the time limit for amending the claims and to be republished in the event of the receipt of amendments.</i>

(54) Title: LOW TEMPERATURE (T LOWER THAN 950 °C) PREPARATION OF MELT TEXTURE YBCO SUPERCONDUCTORS



(57) Abstract

A superconducting material comprising Y-Ba-Cu-O and silver or gold and a method for making that material. The method comprising selecting at least two precursors including CuO, mixing said precursors, melt texturing the formed mixture by heating in a furnace region to no more than about 950 °C, moving said mixture to a lower temperature region, then cooling a resulting sample in a controlled temperature

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**LOW TEMPERATURE (T LOWER THAN 950°C)
PREPARATION OF MELT TEXTURE YBCO SUPERCONDUCTORS**

Field of the Invention

The present invention relates to fabrication methods for high temperature superconducting materials, more particularly to melt texturing fabrication methods for bulk high temperature superconducting materials.

The discovery of high critical temperature superconducting oxides, including a number of materials which superconduct above liquid-nitrogen temperature, has stimulated considerable interest and activity. A limit to application of these materials is the low-critical current density J_c measured in bulk polycrystalline samples. Several fabrication techniques to increase transport J_c have been reported in the conventional literature. Magnetic field alignment, melt-textured growth, and liquid phase methods can significantly enhance J_c values. Currently, further fabrication techniques for the preparation of $\text{YBa}_2\text{Cu}_3\text{O}_x$ superconductors and the products thereof have been proposed. However, if these superconductors are to be practically useful, the transport critical current density should be greater than $10,000 \text{ A/cm}^2$ at liquid nitrogen temperature (77K). These $\text{YBa}_2\text{Cu}_3\text{O}_x$ superconductors obtained from general sintering methods possess a transport critical current density from 150 to 600 A/cm^2 at 77K. However, these values are far below the applicable range. The transport critical current density of a single crystal may be greater than 10^4 A/cm^2 , but the size of the product is small, which cannot be used in practice. The transport critical current

density of epitaxially grown thin films may be greater than 10^6 A/cm^2 , but the film is thin, and the critical current (I_c) can only reach a maximum of about 3 to 5 amp (A). Besides, the thin film must be deposited onto an expensive single crystal substrate. Thus, the product obtained in accordance with prior processes is not very useful.

The brittleness and the weak-link behavior at grain boundaries are two challenging problems hindering most practical applications of bulk copper oxide superconductor materials. The melt texture growth (MTG) method (S. Jin, R.C. Sherwood, E.M. Gyorgy, T.H. Tiefel, R.B. Van Dover, S. Nakahara, L.F. Schneemeyer, R.A. Fastnacht, and M.E. Davis, *Appl. Phys. Lett.* 54, 584 (1989)), melt powder melt growth (MPMG) method (M. Murakami et al, *Modern Phys. Lett. B* 4, 163 (1990)), and other similar methods (K. Salama, V. Selvamanickam, and D.F. Lee, in *Processing and Properties of High T_c Superconductors*, edited by S. Jin (World Scientific, Singapore, 1992)) have been developed to overcome the weak-link problem. On the other hand, incorporation of metallic silver into the copper oxide materials has proven to be critically important, because silver may help overcome the brittleness and also enhance the critical current density. At the present time, long wires made of Bi-Sr-Ca-Cu-O and silver have been fabricated by a number of research groups (K. Sato, N. Shibuta, H. Mukai, T. Hikata, M. Ueyama, and T. Kato, *J. Appl. Phys.* 70, 6484 (1991), K. Togano, H. Kumakura, K. Kadowaki, H. Hitaguchi, H. Maeda, J. Kase, J. Shimoyama, and K. Nomura, *Cryogenic Eng.* 38, 1081 (1992), P. Haldar, J.G. Hoehn, Jr., U. Balachandran, and L.R. Motowidlo, *Proc. Symp. on "Processing of Long Lengths of Superconductors"*, 1993 TMS-AIME Fall Meeting, Pittsburgh, 1993). This success can be attributed to the relatively low melting point of the Bi-Sr-Ca-Cu-O compound and its strong c-axis texture. However, the Bi-Sr-Ca-Cu-O

compound is plagued by the flux creep problem at temperatures above 30 K and in magnetic fields greater than 1 T, limiting its usefulness to a narrow temperature and field range (S. Jin, Proc. Symp. on "Processing of
5 Long Lengths of Superconductors", 1993 TMS-AIME Fall Meeting, Pittsburgh, 1993).

YBa₂Cu₃O_{7-x} (YBCO) has the potential to yield a high critical current density even in very high fields. However, fabrication of long-length wires and cables of
10 YBCO has been hindered by the high melting temperature of YBCO (its peritectic point is approximately 1015°C) which is well above the melting temperature of silver (960°C), making it very difficult to combine silver with the conventional MTG or other similar processes. Fabricating
15 well-textured YBCO in combination with silver below its peritectic point has become of much current interest (S. Jin, Proc. Symp. on "Processing of Long Lengths of Superconductors", 1993 TMS-AIME Fall Meeting, Pittsburgh, 1993; V. Selvamanickam, A. Goyla, and D.M. Kroeger, Appl.
20 Phys. Lett. 65, 639 1994).

SUMMARY OF THE INVENTION

It is an objective of the present invention to provide an improved method for forming bulk copper oxide superconductive materials.

25 More specifically, it is an objective of the invention to form bulk oxide superconductors by a method which overcomes the brittleness and/or weak link behavior at grain boundaries.

It is a further objective of the invention to combine
30 YBCO and silver, in a bulk copper oxide superconductor.

It is a further and more specific objective to provide a method of formulating a melt textured YBCO and silver so that the highest temperature utilized is 950°C, i.e. below the melting point of silver, thereby solving

many of the problems created by the normally high melting temperature of YBCO.

It is a further objective of the invention to provide an effective melt textured growth process for bulk YBCO at
5 temperatures below 950°C so that the material (YBCO) can be combined with silver to produce bulk superconductors in the wires/cables form that can carry superconducting critical current density of 10,000 A/cm² or higher at 77 K.

In summary, according to the method of the present
10 invention, the high preparation temperatures (typically ≥ 1050°C) used in conventional melt textured growth processes are avoided by averting peritectic melting of YBCO. Instead, according to the present invention, a combination of precursors are utilized that provide
15 melting at 950°C or lower temperatures. After melting of the thoroughly mixed precursors, the sample is cooled in a controlled temperature environment. The disclosed process makes it possible to use metallic silver or other normal metals such as gold, as components in the
20 fabrication of long YBCO wires and cables while achieving a high critical current density.

It should be noted that while we have used the symbol YBCO to describe a specific high temperature
superconductor material YBa₂Cu₃O₇, the present invention is
25 useful with many possible modifications of the compound, including complete or partial replacement of the element yttrium (Y) by other rare earth elements, by using differed stoichiometries of Y, Ba, Cu, as well as using different oxygen contents. Also, while silver is highly useful in
30 achieving the goals of this invention and is well adapted to being incorporated in the described process, other normal metals such as gold are also highly useful and are intended to be included within the scope of the invention.

The invention will be better understood by reference
35 to the following figures and the accompanying description of a preferred embodiment.

Fig. 1 The powder X-ray diffraction patterns of a sample prepared by the LTMTG process.

Fig. 2 The SEM micrographs obtained on the fractured surface of a sample.

5 Fig. 3 The critical current density as a function of the applied magnetic field H . The sample has a thin-slab geometry and its thickness is about 1.0 mm. Inset: the hysteresis curves measured at 5 K and 77 K, respectively. For both panels, the vertical axis is the
10 magnetization in units of emu/cc and the horizontal axis is the externally applied magnetic field in units of kOe.

DETAILED DESCRIPTION OF A PREFERRED EMBODIMENT

A new low temperature melt texture growth (LTMTG) process for bulk $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$ is described below as a
15 specific example of the present invention. The high preparation temperature (typically $\geq 1050^\circ\text{C}$) used in the conventional MTG process is eliminated by averting peritectic melting of $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$. Instead, a combination of precursors is used that results in a liquid state at
20 950°C , the highest heating temperature during the LTMTG process. The new preparation procedure makes it possible to use metallic silver as a vital component in the fabrication of long YBCO wires and cables with high critical current densities, therefore promising a great
25 potential for large scale applications of bulk YBCO materials.

Three precursors, $\text{Y}_2\text{BaCuCO}_5$, BaCuO_2 , and BaSnO_3 were first prepared using the solid state reaction method. The detailed starting material compositions and the thermal
30 treatment parameters for these precursors are given in Table I. The LTMTG process began with mixing precursors and commercially available CuO according to the following molecular ratio: $\text{Y}_2\text{BaCuO}_5:\text{BaCuO}_2:\text{CuO}=1:3:5.28$. The excessive use of CuO reflects the essential concept that
35 a proper combination of BaCuO_2 and CuO may result in a

liquid state at 950°C. This liquid state then reacts with the Yttrium rich precursor (Y_2BaCuO_3) to form the desired $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ phase. Preliminary experiments indicate that adding even more CuO may further reduce the melting temperature below 950°C, but the overall normal state and superconducting state properties would be adversely affected if too much CuO were present. To enhance the magnetic flux pinning ability, 5 wt% (with respect to the total weight of Y_2BaCuO_3 , BaCuO_2 , and CuO) of BaSnO_3 precursor was added to the mixture. After thorough mixing and grinding, the precursors were pressed into rectangular pellets with dimensions 24 x 8 x 2 mm³. The pellets were loaded into an alumina crucible with a platinum wire attached. The crucible was quickly introduced into a tube furnace preheated to 950°C with a temperature gradient 3.5°C/cm. A slow motor was used to pull the platinum wire so that the crucible gradually moved to the lower temperature region. The motor rotated one revolution per 24 hours, corresponding to a crucible travelling speed of 0.3 cm/hour. After the crucible travelled for 72 hours (with the sample temperature at approximately 874°C), the slow motor was turned off. The samples were then allowed to cool to 480°C (15°C/h). Oxygen annealing was carried out at 480°C for 24 h. As prepared pellets appeared to be noticeably smaller than the raw pellets, mainly because of the solidification of grains but also, partially, because of the loss of a small amount of Ba and Cu rich liquid.

Standard dc four-probe measurements were performed to determine the superconducting transition temperature T_c and the normal state resistivity ρ . The resistive superconducting transition is very sharp, characteristic of the dominant $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ phase. Detailed data of T_c and ρ are presented in Table II. The normal state resistivity of our samples is approximately four times that of pure bulk $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$, suggesting the existence of some impurity phases. The phase structure of the samples was examined

by powder X-ray diffraction technique using a Sintag diffractometer with characteristic copper K α radiation of wavelength 1.5490 Å. A scanning electron microscope (SEM) was used to analyze the sample microstructure. The critical current density was studied by measuring the magnetization by hysteresis curves at 77 K and 5 K, using a Lake Shore 7229 DC Magnetometer. We are indebted to B.C. Dodrill at Lake Shore Cryotronics, Inc. for help in the magnetization measurements.

Fig. 1 is the powder X-ray diffraction pattern of samples prepared by the LTMTG method. A major phase of YBa₂Cu₃O_{7- δ} perovskite structure is the dominant phase and a second phase of Y₂BaCuO₅ is also clearly seen. The presence of BaSnO₃ is indicated by the feature near $2\theta=30.1^\circ$. The spectrum lines of the YBa₂Cu₃O_{7- δ} phase were all indexed and the d spacings of these lines were determined from the diffraction pattern. The lattice constants were calculated using a least-squares fit program. The results are listed in Table III, showing a clear orthorhombic structure for YBa₂Cu₃O_{7- δ} . The Y₂BaCuO₅ phase in Fig. 1 makes a rather large contribution. Since Y₂BaCuO₅ is an electrically insulating phase, its existence is consistent with the large normal state electrical resistivity shown in Table II.

Fig. 2 shows a SEM micrograph taken on a fractured surface of a sample prepared by the LTMTG process. It can be seen that there are essentially no voids present, which is a desirable result of melting at 950°C followed by directional solidification. The main structural feature in Fig. 2 is the layered platelet structure of YBa₂Cu₃O_{7- δ} . The typical layer thickness of the YBa₂Cu₃O_{7- δ} plates ranges from 15 to 30 μm . The formation of the platelet structure is clear evidence of successful melt textured growth. The alignment of the YBa₂Cu₃O_{7- δ} plates is highly favorable for achieving large critical current density because it may effectively reduce the weak link behavior at grain

boundaries. There are some round and sharp edged particles present with the particle size ranging between 5 to 15 μm . These particles may represent the Y_2BaCuO_5 , BaSnO_3 , and other minor Ba-Cu rich phases.

5 In Fig. 3 the critical current density (J_c) data is plotted as a function of the externally applied magnetic field (H). The critical current density was calculated from the DC magnetization hysteresis curves shown in the inset, using Bean's critical state model (C.P. Bean, Phys.
10 Rev. Lett. 8, 250, 1962). For the 77 K measurement, $J_c = 1.1 \times 10^4 \text{ A/cm}^2$ at $H=0$. The magnitude of J_c slowly decreases with the applied magnetic field. When H is above 0.5 kOe, J_c decreases more rapidly with H . At $H=1$ kOe, $J_c/J_c(H=0)$ is approximately 35%. For the 5 K
15 measurement, we obtain a larger value $J_c = 2.7 \times 10^5 \text{ A/cm}^2$ at $H=0$ and J_c does not decrease significantly with H until 40 kOe. The J_c values of these samples are about 100 times higher than those of sintered YBCO, and approximately a factor of 2 smaller than the fully optimized results
20 obtained on small samples prepared by the conventional MTG process. This LTMTG technique will allow the use of metallic silver to fabricate composite cables and wires of YBCO that have the best superconducting critical density of the copper oxide superconductors over a wide
25 temperature and magnetic field range.

In summary, the above is an example of a new low temperature melt texture growth (LTMTG) process for bulk $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$. The highest heating temperature in this process is 950°C. This LTMTG process makes it feasible,
30 in practice, to incorporate metallic silver in the fabrication of long YBCO wires and cables. This process provides an effective solution to the problems of the brittleness and the low critical current density in bulk $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$, bringing large scale applications of bulk YBCO
35 materials one step closer to reality.

It can be seen that with appropriate selection of precursors that a superconductor represented by the following $RE_nBa_mCu_pO_q\lambda_q$ can be formulated, where

RE = Y, La, Nd, Sm, Eu, Gd, Dy, Ho, Er, Tm, Yb, Lu,
5 or any combination of above where λ = a non rare earth metal such as preferably Ag and Au

n = pref 1

m = pref 2

o = pref 3

10 p = pref 6.8 - 7.0

q = 0-50

Examples of alternative stoichiometries could thus be:



15 Other alternations to the present invention may be apparent to a person of skill in the art who studies the present invention disclosure. Therefore the invention should be limited only by the following claims.

Table I. Preparations for the three precursors. The starting materials are commercially available oxide powders with purity 99.9% or better.

Precursor Name	Starting materials and molecular ratios	Thermal treatment
Y_2BaCuO_5	$\text{Y}_2\text{O}_3:\text{BaCO}_3:\text{CuO}=1:1:1$	900°C in air, 12 h
5 BaCuO_2	$\text{BaCO}_3:\text{CuO}=1:1$	900°C in air, 12 h
BaSnO_3	$\text{BaCO}_3:\text{SnO}_2=1:1$	900°C in air, 16 h

Table II. The superconducting transition temperature and electrical resistivity data.

T_c	89.5 K
transition width	< 1.5K
10 resistivity at 100 K	2.42 mΩ•cm
	5.64 mΩ•cm

Table III. The lattice constants of the $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$ phase (all in units of Å).

a	b	c
3.8140 ± 0.0031	3.8806 ± 0.0024	11.6435 ± 0.0074

WHAT IS CLAIMED IS:

1. A superconducting material comprising YBCO and silver or gold.
2. A superconducting material as claimed in Claim 1
5 wherein YBCO is $\text{REBa}_2\text{Cu}_3\text{O}_{7-x}$ where RE = Y, La, Nd, Sm, Eu, Gd, Dy, Ho, Er, Tm, Yb, Lu, or any combination of above.
3. A method for making superconducting material comprising YBCO and silver comprising selecting at least two precursors including CuO, mixing said precursors to
10 form a mixture to be processed, melt texturing said mixture by heating said mixture in a furnace region heating to no more than about 950°C, and moving said mixture slowly to a lower temperature region, then cooling a resulting sample in a controlled temperature
15 environment.
4. The method of Claim 3 wherein one of said precursors included BaCuO_2 and the other of said precursors includes CuO.
5. The method of Claim 4 wherein one of said precursors
20 is Y_2BaCuO_5 .
6. The method of Claim 4 further including the step of adding a BaSnO_3 precursor to the mixture to enhance magnetic flux pinning ability.
7. The method of Claim 5 wherein said precursors are
25 present in a ratio of about 5.28:3:1.
8. The method of Claim 7 wherein said mixture includes the step of adding further CuO.

9. The method of Claim 4 wherein said heating step occurs in a tube furnace having a temperature at the region where the mixture is introduced of about 950°C, and a temperature gradient of 2 to 10°C/cm.

5 10. The method of Claim 9 wherein the mixture during the melt textured growth process, moves from said region of 950°C to a region of 874°C.

11. The method of Claim 10 wherein said mixture, following said melt textured growth, is cooled at a
10 controlled rate to about 480°C.

12. The method of Claim 11 wherein said cooled, treated mixture is oxygen annealed.

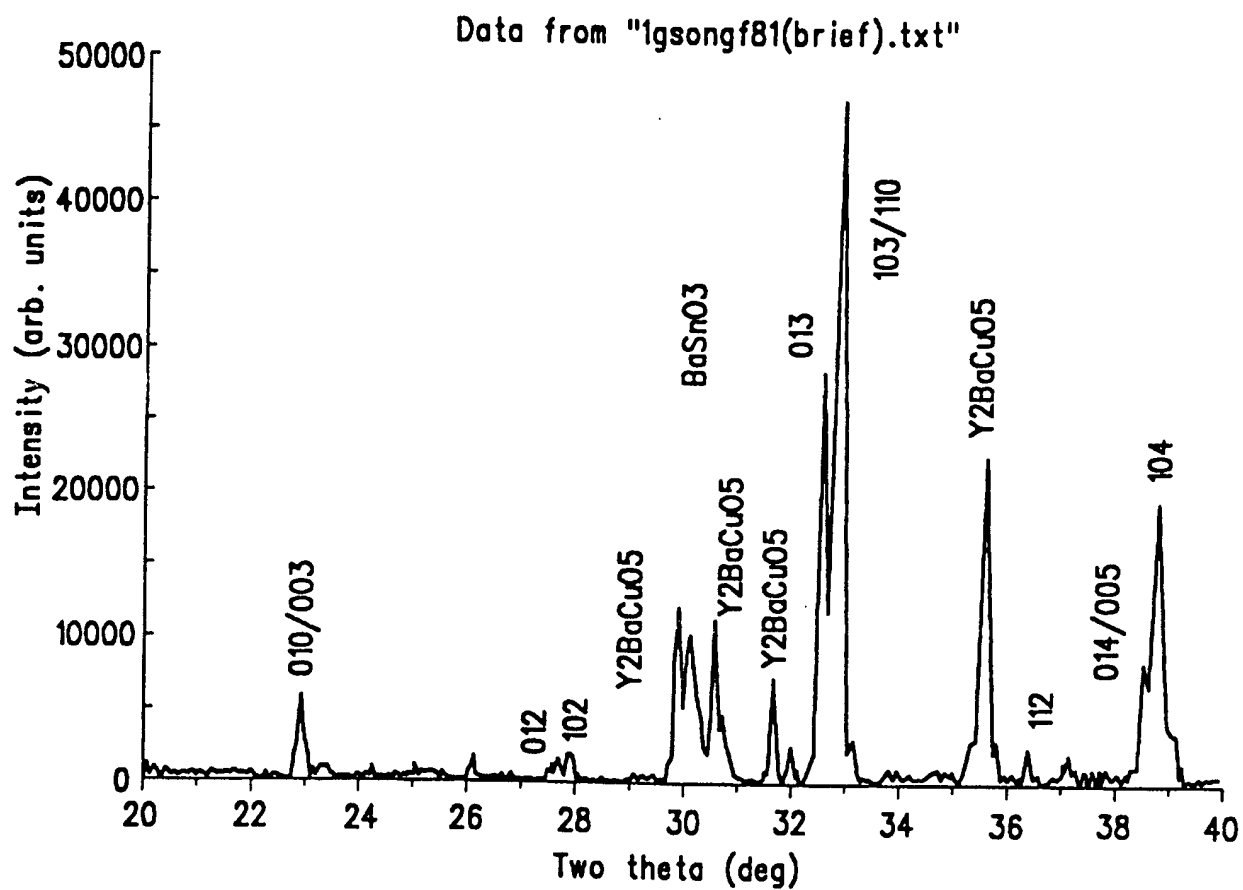


FIG. 1



FIG. 2

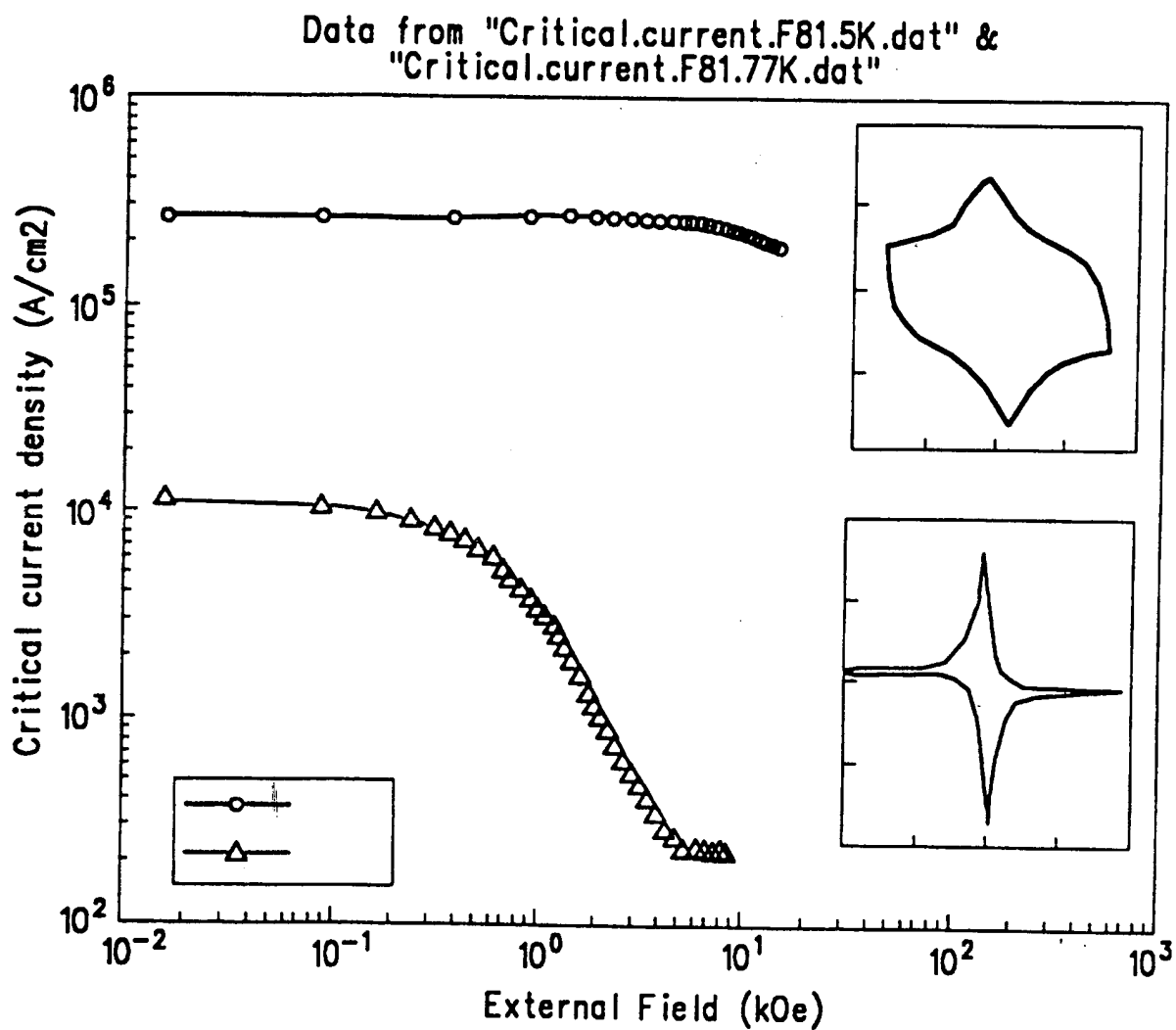


FIG. 3

INTERNATIONAL SEARCH REPORT

International Application No
PCT/US 95/16995

A. CLASSIFICATION OF SUBJECT MATTER
IPC 6 C04B35/45 C04B35/653 H01L39/24

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
IPC 6 C04B H01L

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	EP,A,0 376 276 (NGK SPARK PLUG CO., LTD) 4 July 1990 see page 3, line 35 - page 4, line 37; claims 1-12; figures 1,2; table 1	1-3
Y	---	4,5
X	DE,A,41 14 976 (INSTITUT FÜR FESTKÖRPER- UND WERKSTOFFFORSCHUNG DRESDEN EV.) 11 February 1993 see the whole document	1-3
Y	---	4,5
X	DE,A,41 14 975 (G. RISSE, M. UELTZEN, D. VÖLTZKE) 5 November 1992 see column 1, line 64 - column 2, line 21; claims 1,6; example 2	1-3
Y	---	4,5
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☒ Patent family members are listed in annex.

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Date of the actual completion of the international search

12 June 1996

Date of mailing of the international search report

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INTERNATIONAL SEARCH REPORT

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C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
Y	EP,A,0 474 566 (CNRS) 11 March 1992 see column 4, line 51 - column 6, line 8; claim 5 -----	4,5

INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No

PCT/US 95/16995

Patent document cited in search report	Publication date	Patent family member(s)	Publication date
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		JP-B- 7055858	14-06-95
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		DE-T- 68922290	21-09-95
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DE-A-4114976	11-02-93	NONE	
DE-A-4114975	05-11-92	NONE	
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